

L Number	Hits	Search Text	DB	Time stamp
1	140	(power adj plant) and (gear adj reduction)	USPAT; US-PGPUB	2003/04/11 14:39
2	51	((power adj plant) and (gear adj reduction)) and turbine	USPAT; US-PGPUB	2003/04/11 14:39
4	2	((((power adj plant) and (gear adj reduction)) and turbine) and mount\$4) and transportation	USPAT; US-PGPUB	2003/04/11 14:40
3	44	((power adj plant) and (gear adj reduction)) and turbine) and mount\$4	USPAT; US-PGPUB	2003/04/11 14:40
-	258	(60/796).CCLS.	USPAT; US-PGPUB	2003/04/11 10:22
-	20692	power adj plant	USPAT; US-PGPUB	2003/04/11 14:38
-	18	((60/796).CCLS.) and (power adj plant)	USPAT; US-PGPUB	2003/04/11 10:27
-	4	("2124395"   "3005518"   "3290793"   "3623573").PN.	USPAT	2003/04/11 10:26
-	3	((60/796).CCLS.) and transportation	USPAT; US-PGPUB	2003/04/11 10:31
-	2	("3418485"   "4002023").PN.	USPAT	2003/04/11 10:29
-	1834	(power adj plant) and transportation	USPAT; US-PGPUB	2003/04/11 13:03
-	135	(power adj plant) and (transportation near vehicle)	USPAT; US-PGPUB	2003/04/11 12:56
-	6	("2432228"   "2541288"   "3228352"   "3285194"   "3369684"   "3584584").PN.	USPAT	2003/04/11 10:56
-	15	truck same (gas adj turbine) same mount\$4	USPAT; US-PGPUB	2003/04/11 12:51
-	2	jp-2001173408-\$.did.	EPO; JPO; DERWENT; IBM_TDB	2003/04/11 11:23
-	2	jp-11062621-\$.did.	EPO; JPO; DERWENT; IBM_TDB	2003/04/11 11:39
-	2	jp-11013416-\$.did.	EPO; JPO; DERWENT; IBM_TDB	2003/04/11 11:26
-	1	jp-59224407-\$.did.	EPO; JPO; DERWENT; IBM_TDB	2003/04/11 11:39
-	7	("RE30280" "RE30229" "3925679" "3720446" "3770232" "4385774" "4245135" "4245135").PN.	USPAT; US-PGPUB	2003/04/11 12:53
-	3	("3461633"   "3489911"   "3848138").PN.	USPAT	2003/04/11 12:54
-	38	turbine same (transportation near vehicle)	USPAT; US-PGPUB	2003/04/11 14:01
-	973	((power adj plant) and transportation) and mount\$4	USPAT; US-PGPUB	2003/04/11 13:04
-	115	((power adj plant) and transportation) and mount\$4) and modular	USPAT; US-PGPUB	2003/04/11 13:04
-	2	("1522612"   "2086036").PN.	USPAT	2003/04/11 13:21
-	16	(power adj plant) same (transportation near vehicle)	EPO; JPO; DERWENT; IBM_TDB	2003/04/11 14:02
-	3	turbine same (transportation near vehicle)	EPO; JPO; DERWENT; IBM_TDB	2003/04/11 14:04
-	11	turbine same (transportation near vehicle)	USOCR	2003/04/11 14:16
-	119313	(29/\$).CCLS.	USPAT; US-PGPUB	2003/04/11 14:17
-	0	("25 and power adj plant").PN.	USPAT; US-PGPUB	2003/04/11 14:17
-	374	((29/\$).CCLS.) and power adj plant	USPAT; US-PGPUB	2003/04/11 14:21
-	28	((29/\$).CCLS.) and power adj plant) and truck	USPAT; US-PGPUB	2003/04/11 14:21

-	58626	(60/\$).CCLS.	USPAT; US-PGPUB	2003/04/11 14:21
-	3422	((60/\$).CCLS.) and power adj plant	USPAT; US-PGPUB	2003/04/11 14:21
-	180	((((60/\$).CCLS.) and power adj plant) and truck	USPAT; US-PGPUB	2003/04/11 14:21
-	139	(((((60/\$).CCLS.) and power adj plant) and truck) and turbine	USPAT; US-PGPUB	2003/04/11 14:21
-	74	((((((60/\$).CCLS.) and power adj plant) and truck) and turbine) and mount\$4	USPAT; US-PGPUB	2003/04/11 14:22

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Most Frequently Occurring Classifications of Patents Returned  
From A Search of 10081202 on April 11, 2003

Original Classifications

- 2 330/149
- 2 330/264
- 2 330/277
- 2 330/288
- 2 330/300
- 2 330/51

Cross-Reference Classifications

- 8 330/311
- 3 257/E29.032
- 3 330/255
- 2 257/E29.026
- 2 323/314
- 2 327/434
- 2 330/257
- 2 330/258
- 2 330/260
- 2 330/263
- 2 330/265
- 2 330/294
- 2 330/296
- 2 330/306

Combined Classifications

- 9 330/311
- 4 330/255
- 3 257/E29.032
- 3 330/263
- 3 330/264
- 3 330/265
- 3 330/277
- 3 330/300
- 2 257/E29.026
- 2 323/314
- 2 323/316
- 2 327/377
- 2 327/432
- 2 327/434
- 2 330/149
- 2 330/256
- 2 330/257
- 2 330/258
- 2 330/260

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2 330/274  
2 330/286  
2 330/288  
2 330/294  
2 330/296  
2 330/306  
2 330/51  
2 331/116R  
2 363/132

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Titles of Most Frequently Occurring Classifications of Patents Returned

From A Search of 10081202 on April 11, 2003

9	330/311	(1 OR, 8 XR)	
	Class 330 :	AMPLIFIERS	
	330/250	WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,	
		TRANSISTOR)	
	330/310	.Including plural stages cascaded	
	330/311	..Having different configurations	
4	330/255	(1 OR, 3 XR)	
	Class 330 :	AMPLIFIERS	
	330/250	WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,	
		TRANSISTOR)	
	330/252	.Including differential amplifier	
	330/255	..Having push-pull amplifier stage	
3	257/E29.032	(0 OR, 3 XR)	
	Class 257 :	ACTIVE SOLID-STATE DEVICES	
	257/E29.001	DETAILS OF SEMICONDUCTOR BODIES OR ELECTRODES	
		OF SEMICONDUCTOR DEVICES ADAPTED FOR RECTIFYING,	
		AMPLIFYING, OSCILLATING OR SWITCHING,	
		OR CAPACITORS OR	
		RESISTORS WITH AT LEAST ONE POTENTIAL	
		BARRIER OR SURFACE	
		BARRIER (E.G., PN JUNCTION DEPLETION L	
		AYER OR CARRIER	
		CONCENTRATION LAYER) (EPO)	
	257/E29.002	.Electrical characteristics due to properties	
		of entire semiconductor body rather than just surface	
		region (EPO)	
	257/E29.005	..Characterized by specified shape or size of	
		PN junction or by specified impurity concentration gradient	
		within device (EPO)	
	257/E29.029	...With semiconductor regions connected to	
		electrode carrying current to be rectified, amplified, or	
		switched and such electrode being part of	
		semiconductor	
		device which comprises three or more electrodes (EPO)	
	257/E29.03	....Emitter regions of bipolar transistors	
		(EPO)	

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257/E29.032 .....Noninterconnected multiemitter structures  
(EPO)

3 330/263 (1 OR, 2 XR)  
Class 330 : AMPLIFIERS  
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,  
TRANSISTOR)  
330/262 .Including push-pull amplifier  
330/263 ..Having complementary symmetry

3 330/264 (2 OR, 1 XR)  
Class 330 : AMPLIFIERS  
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,  
TRANSISTOR)  
330/262 .Including push-pull amplifier  
330/263 ..Having complementary symmetry  
330/264 ...And field effect transistor

3 330/265 (1 OR, 2 XR)  
Class 330 : AMPLIFIERS  
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,  
TRANSISTOR)  
330/262 .Including push-pull amplifier  
330/263 ..Having complementary symmetry  
330/265 ...And feedback means

3 330/277 (2 OR, 1 XR)  
Class 330 : AMPLIFIERS  
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,  
TRANSISTOR)  
330/277 .Including field effect transistor

3 330/300 (2 OR, 1 XR)  
Class 330 : AMPLIFIERS  
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,  
TRANSISTOR)  
330/299 .Including combined diverse-type semiconductor  
device  
330/300 ..Bipolar or unipolar (FET)

2 257/E29.026 (0 OR, 2 XR)  
Class 257 : ACTIVE SOLID-STATE DEVICES  
257/E29.001 DETAILS OF SEMICONDUCTOR BODIES OR ELECTRODES  
OF SEMICONDUCTOR DEVICES ADAPTED FOR RE  
CTIFYING,  
AMPLIFYING, OSCILLATING OR SWITCHING, O  
R CAPACITORS OR  
RESISTORS WITH AT LEAST ONE POTENTIAL B

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ARRIER OR SURFACE

BARRIER (E.G., PN JUNCTION DEPLETION LA

YER OR CARRIER

CONCENTRATION LAYER) (EPO)

257/E29.002 .Electrical characteristics due to properties  
of entire semiconductor body rather than

just surface

region (EPO)

257/E29.005 ..Characterized by specified shape or size of  
PN junction or by specified impurity conc

entration gradient

within device (EPO)

257/E29.024 ...Characterized by shape, relative sizes or  
dispositions of semiconductor regions or j

unctions between

regions (EPO)

257/E29.026 ....Surface layout of the device (EPO)

2 323/314 (0 OR, 2 XR)

Class 323 : ELECTRICITY: POWER SUPPLY OR REGULATION  
SYSTEMS

323/304 SELF-REGULATING (E.G., NONRETROACTIVE)

323/311 .Using a three or more terminal semiconductive  
device as the final control device

323/312 ..For current stabilization

323/313 ...To derive a voltage reference (e.g., band  
gap regulator)

323/314 ....With additional stage

2 323/316 (1 OR, 1 XR)

Class 323 : ELECTRICITY: POWER SUPPLY OR REGULATION  
SYSTEMS

323/304 SELF-REGULATING (E.G., NONRETROACTIVE)

323/311 .Using a three or more terminal semiconductive  
device as the final control device

323/312 ..For current stabilization

323/315 ...Including parallel paths (e.g., current  
mirror)

323/316 ....With amplifier connected to or between  
current paths

2 327/377 (1 OR, 1 XR)

Class 327 : MISCELLANEOUS ACTIVE ELECTRICAL NONLINEAR  
DEVICES, CIRCUITS, AND SYSTEMS

327/365 GATING (I.E., SWITCHING INPUT TO OUTPUT)

327/374 .Accelerating switching

327/377 ..Turn-off

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- 2 327/432 (1 OR, 1 XR)
  - Class 327 : MISCELLANEOUS ACTIVE ELECTRICAL NONLINEAR DEVICES, CIRCUITS, AND SYSTEMS
  - 327/365 GATING (I.E., SWITCHING INPUT TO OUTPUT)
  - 327/419 .Utilizing three or more electrode solid-state device
  - 327/427 ..Field-effect transistor
  - 327/432 ...With bipolar transistor
  
- 2 327/434 (0 OR, 2 XR)
  - Class 327 : MISCELLANEOUS ACTIVE ELECTRICAL NONLINEAR DEVICES, CIRCUITS, AND SYSTEMS
  - 327/365 GATING (I.E., SWITCHING INPUT TO OUTPUT)
  - 327/419 .Utilizing three or more electrode solid-state device
  - 327/427 ..Field-effect transistor
  - 327/434 ...Insulated gate FET (e.g., MOSFET, etc.)
  
- 2 330/149 (2 OR, 0 XR)
  - Class 330 : AMPLIFIERS
  - 330/149 HUM OR NOISE OR DISTORTION BUCKING INTRODUCED INTO SIGNAL CHANNEL
  
- 2 330/256 (1 OR, 1 XR)
  - Class 330 : AMPLIFIERS
  - 330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G., TRANSISTOR)
  - 330/252 .Including differential amplifier
  - 330/256 ..Having temperature compensation means
  
- 2 330/257 (0 OR, 2 XR)
  - Class 330 : AMPLIFIERS
  - 330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G., TRANSISTOR)
  - 330/252 .Including differential amplifier
  - 330/257 ..Having current mirror amplifier
  
- 2 330/258 (0 OR, 2 XR)
  - Class 330 : AMPLIFIERS
  - 330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G., TRANSISTOR)
  - 330/252 .Including differential amplifier
  - 330/258 ..Having common mode rejection circuit
  
- 2 330/260 (0 OR, 2 XR)
  - Class 330 : AMPLIFIERS
  - 330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G., TRANSISTOR)



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- 330/252 .Including differential amplifier  
330/260 ..Having signal feedback means
- 2 330/274 (1 OR, 1 XR)  
Class 330 : AMPLIFIERS  
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,  
TRANSISTOR)  
330/262 .Including push-pull amplifier  
330/273 ..Having particular biasing arrangement  
330/274 ...To eliminate crossover distortion
- 2 330/286 (1 OR, 1 XR)  
Class 330 : AMPLIFIERS  
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,  
TRANSISTOR)  
330/286 .Including distributed parameter-type coupling
- 2 330/288 (2 OR, 0 XR)  
Class 330 : AMPLIFIERS  
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,  
TRANSISTOR)  
330/288 .Including current mirror amplifier
- 2 330/294 (0 OR, 2 XR)  
Class 330 : AMPLIFIERS  
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,  
TRANSISTOR)  
330/291 .Including signal feedback means  
330/294 ..Having frequency-responsive means or  
phase-shift means in feedback path
- 2 330/296 (0 OR, 2 XR)  
Class 330 : AMPLIFIERS  
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,  
TRANSISTOR)  
330/296 .Including particular biasing arrangement
- 2 330/306 (0 OR, 2 XR)  
Class 330 : AMPLIFIERS  
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,  
TRANSISTOR)  
330/302 .Including frequency-responsive means in the  
signal transmission path  
330/306 ..And bandpass, broadband (e.g., wideband) or  
sidepass means
- 2 330/51 (2 OR, 0 XR)

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Class 330 : AMPLIFIERS  
 330/51 COMBINED WITH AUTOMATIC AMPLIFIER DISABLING  
 SWITCH MEANS

2 331/116R (1 OR, 1 XR)

Class 331 : OSCILLATORS  
 331/107R SOLID STATE ACTIVE ELEMENT OSCILLATOR  
 331/108R .Transistors  
 331/116R ..Electromechanical resonator controlled

2 363/132 (1 OR, 1 XR)

Class 363 : ELECTRIC POWER CONVERSION SYSTEMS  
 363/25 ....With automatic control of the magnitude o

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output voltage or current  
 363/123 .Using semiconductor-type converter  
 363/131 ..In transistor inverter systems  
 363/132 ...Bridge type